

Theme 4:

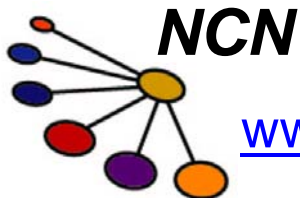
(Device) Theory and Modeling

Mark Lundstrom

Network for Computational Nanotechnology

Birck Nanotechnology Center, Purdue University

West Lafayette, IN



www.nanohub.org

theme 4 team

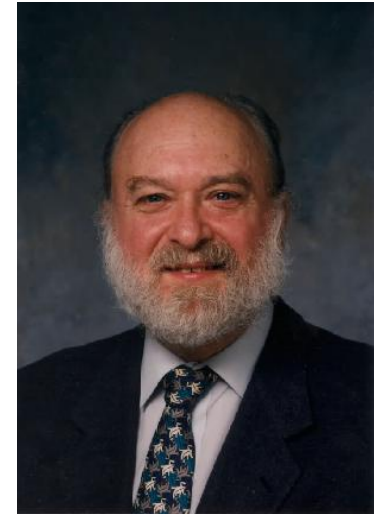
- 1) James Raynolds (Albany)
-electrically-based spin switching in hetero-dimen. quantum dot devices
- 2) Alex Xue (Albany)
-quantum molecutronics
- 3) Michael Shur (RPI)
-plasmonic devices
- 4) Azad Naeemi (Georgia Tech)
-graphene interconnects and devices
- 5/6) Mark Lundstrom / Supriyo Datta / NCN@Purdue
-graphene electronics + NCN@Purdue leverage

“exploratory simulation”

“Excellent computer simulations are done for a purpose...

“*exploratory simulation*”

- 1) to **explore** uncharted territory
- 2) to **resolve** a well-posed scientific or technical question
- 3) to make a good **design** choice.”



L.P. Kadanov, “Excellence in Computer Simulation,” *Computing in Science and Engineering*, (Mar./Apr. 2004).

simulation philosophy



refine ideas
generate new
ideas

develop
sophisticated
simulations
step-by-step

bring understanding back

Network for Computational Nanotechnology

NCN@Norfolk State

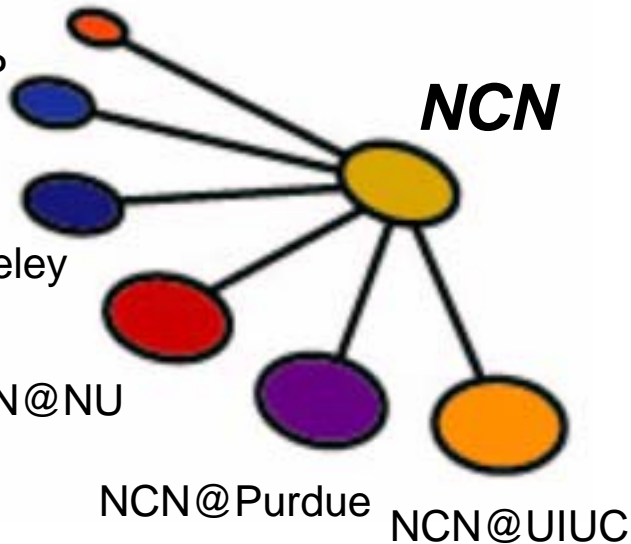
NCN@UTEP

NCN@Berkeley

NCN@NU

NCN@Purdue

NCN@UIUC



Mission:

to connect those who develop simulations with those who use them in research

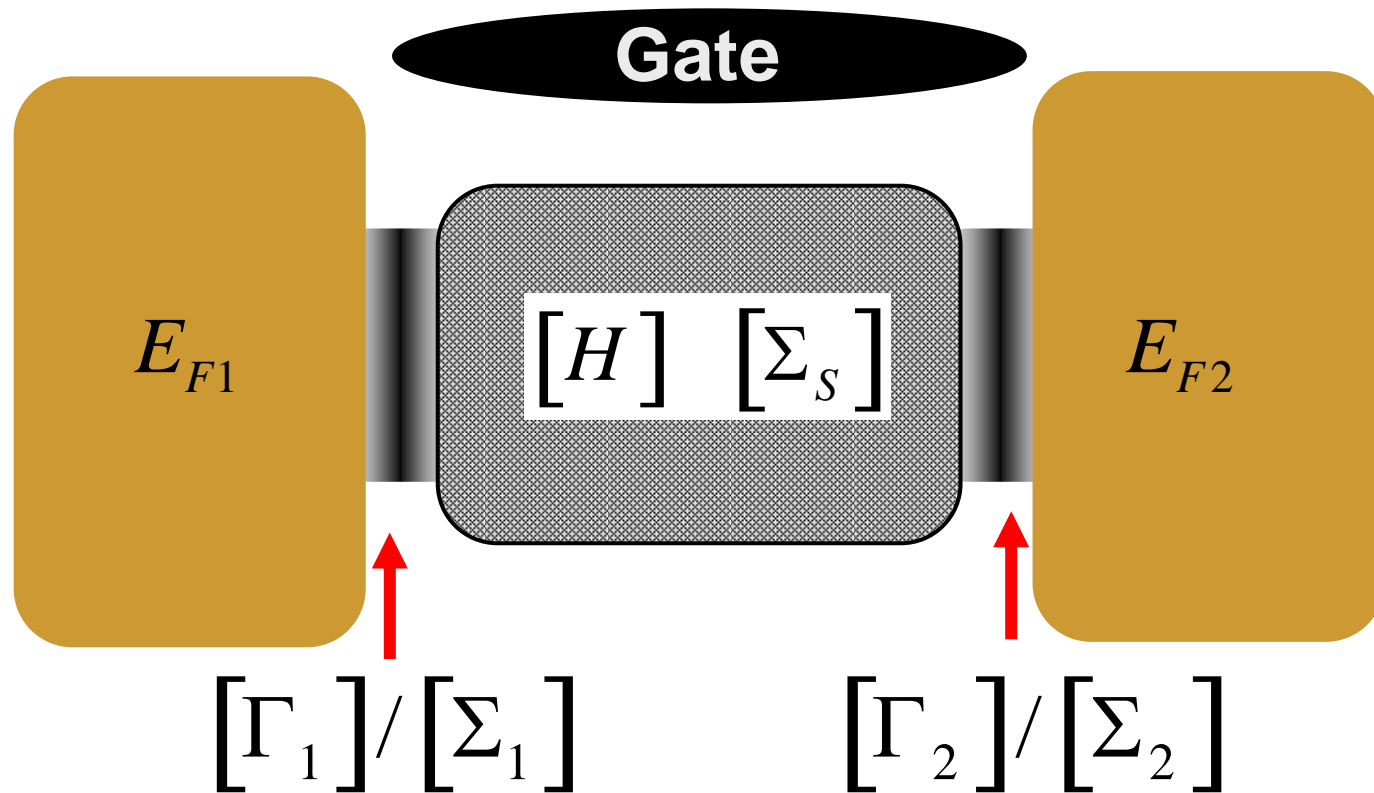
Key strategy:

cyberinfrastructure



an *'infrastructure and research network'*

generic model to NEGF

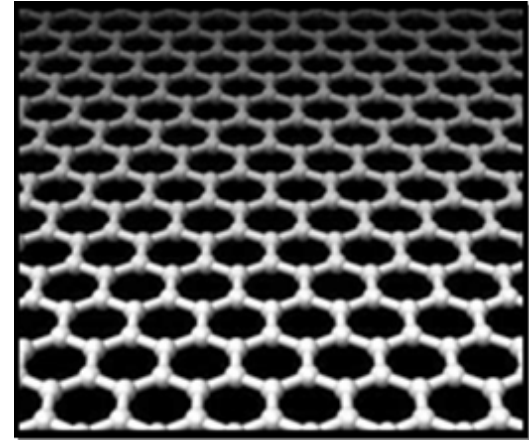


S. Datta, *Quantum Transport: Atom to Transistor*, Cambridge, 2005

("Concepts of Quantum Transport" nanohub.org)

NEGF simulation

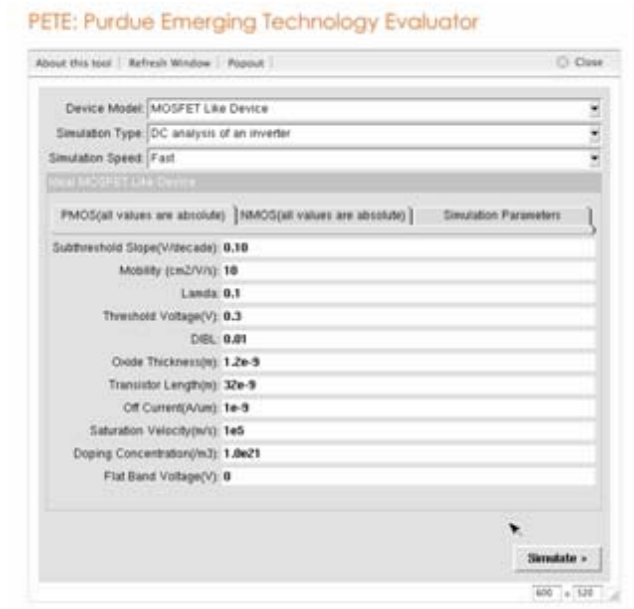
- molecular electronics
- semiconductor nanoelectronics
- spintronics
- electronic / magnetic devices



<http://en.wikipedia.org/wiki/Graphene>

graphene

benchmarking with PETE

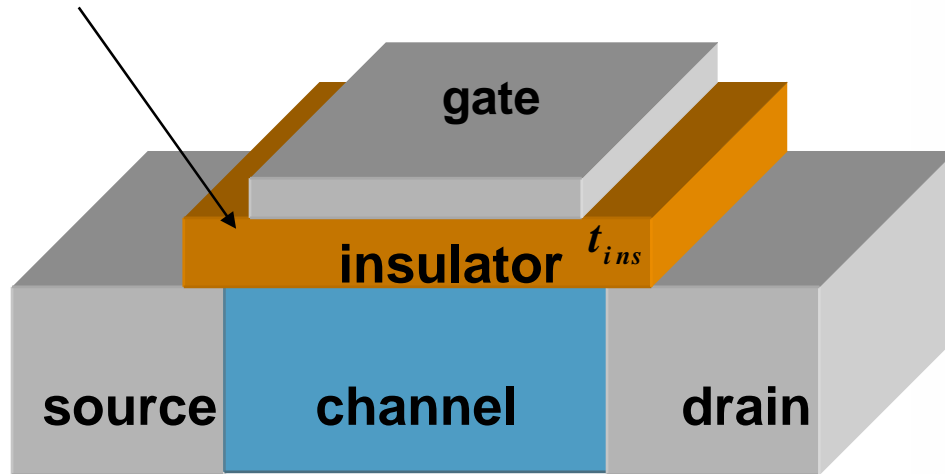


Purdue Exploratory Technology Evaluator Kaushik Roy (Purdue)

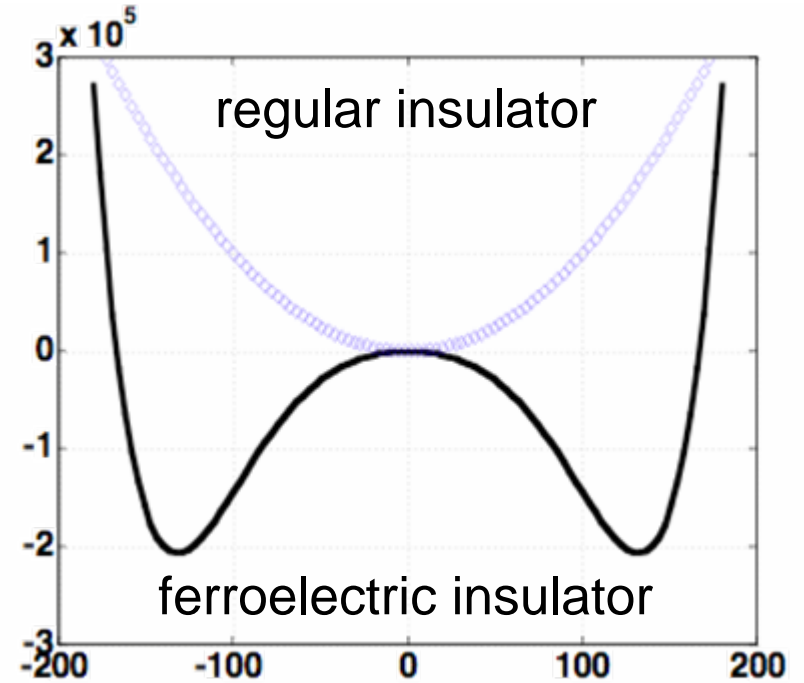
- table-based models
- validated against Spice
- speed / power assessment for benchmark circuits
- available on nanoHUB.org

FE FET

FE gate insulator



S. Salahuddin and S. Datta,
Nano Letters, Feb., 2008



$$U = \frac{Q^2}{2C}$$

rappture.org and HUBzero.org shared infrastructure

Rappture



Simulation Code



researcher

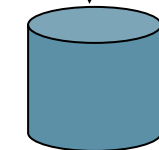
CNTbands 2.0

Structure: Carbon Nanotube

Simulation Method: Pz orbital

Chirality axes: n: 7, m: 7

Model parameters: Tight Binding Energy: 3eV, Carbon-carbon spacing: 1.42Å, Length in 3-D view: 15



Content Database

Maxwell's Daemon

grid



nanoHUB

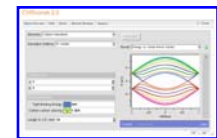
CNTbands 2.0

user



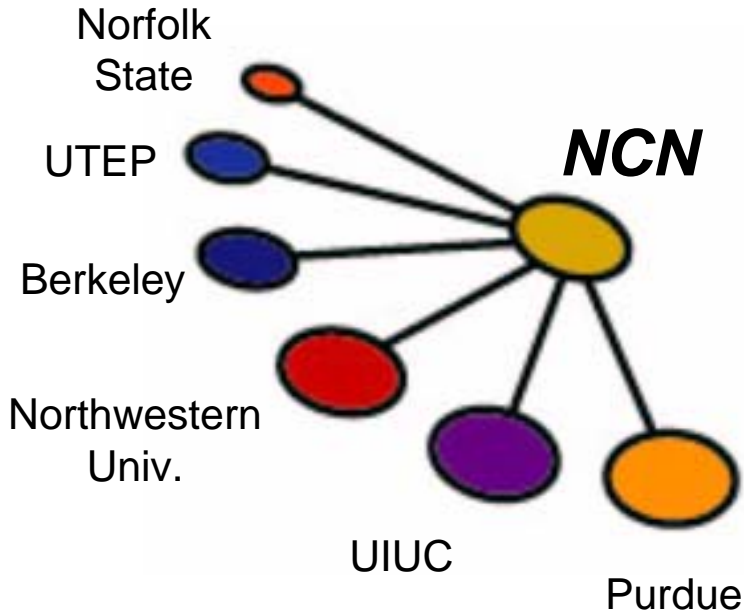
Physical Machine

Virtual Machine



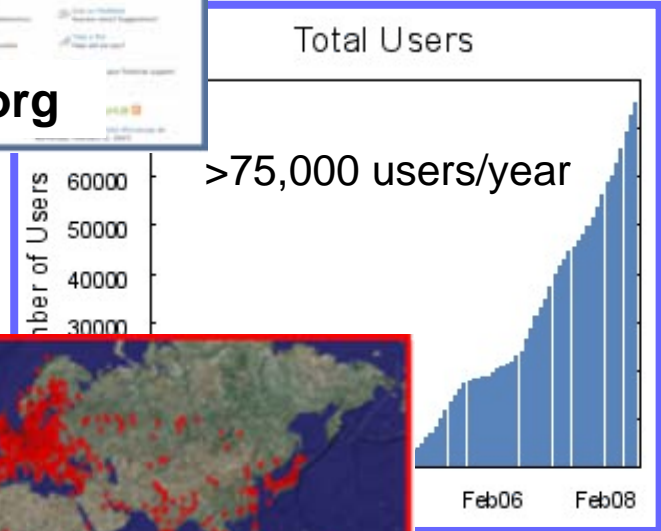
rendering farm

Network for Computational Nanotechnology



NSF/NRI - NCN

- techniques for exploratory simulation
- new ideas for switching devices
- technology for dissemination and collaborations



theme 4 team

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James Reynolds



Technical focus: QD Spin Devices

Approach:

Finite-element based simulations of realistic devices

Key result:

Electrical spin switching/enhancement due to asymmetric confining potentials

INDEX Student:

Sanjay Prabhakar

Talk in QD Spin Device Session

Poster by: *Sanjay Prabhakar*

Michael Shur



Technical focus: *THz plasmonic devices*

Approach:

Solving Maxwell equations and equations describing ballistic transport and THz characterization

Key result:

Si THz detection with nanoscale resolution

INDEX Student:
Bill Stillman

Poster by M. Shur: “Modeling and Characterization of THz Plasma Electronic Devices”

Yongqiang (Alex) Xue



Technical focus: Quantum Moletronics

Approach:

develop and apply density functional and Schwinger-Keldysh Green's function methods

Key result:

hydrogen passivation effect on silicon nanowires

INDEX Student:
Abraham Hmiel

Poster by: ***Abraham Hmiel***

Azad Naeemi



Technical focus: graphene interconnects and devices

Approach:

quantify physical limits of various computational variables from interconnection point of view to identify the promising options

Key result:

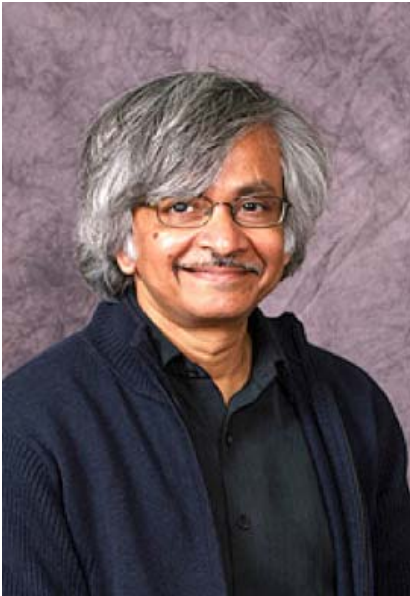
quantum conductance modeling for GNRs

INDEX Student:

Shaloo Rakheja

***Talk in Graphene Session**

Supriyo Datta



Technical focus: Graphene

Approach:

extend and apply NEGF formalism

Key result:

role of MIGS states in graphene

***Talk in Graphene Session**

INDEX Students:

R. Golizadeh-Mojarad

Tony Low (pending)

***Posters by:**

Roksana Golizadeh-Mojarad

and Tony Low

Mark Lundstrom



Students:

Tony Low (pending)
Dionisis Berbedes

Technical focus: Graphene devices

Approach:

apply NEGF formalism, percolation theory, and assess and benchmark device concepts

Key result:

quantitative understanding of graphene PN junction IV

Poster by: ***Tony Low***

Summary

- 1) Focus on exploratory simulation and tight connections to experimental work.
- 2) NSF-NRI program provides additional leverage.
- 3) nanoHUB provides infrastructure support available to Theme 4 and the NRI program.